

View Online at <https://aerobasegroup.com/nsn/5961-01-365-5033>

Inclosure Material:

Metal

Overall Length:

0.820 inches

Overall Height:

0.275 inches

Overall Width:

0.690 inches

Mounting Facility Quantity:

1

Component Name And Quantity:

1 semiconductor device diode and 1 transistor

Mounting Method:

Unthreaded hole

Features Provided:

Electrostatic sensitive and hermetically sealed case

Semiconductor Material:

Silicon single transistor

Voltage Rating In Volts Per Characteristic:

500.0 drain to source voltage single transistor

Current Rating Per Characteristic:

4.50 amperes forward current, dc single semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

80.0 degrees celsius ambient air

Special Features:

Single semiconductor device diode junction pattern arrangement: pn

Terminal Type And Quantity:

5 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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